

CSM3400S23

30V N-Channel Enhancement Mode MOSFET

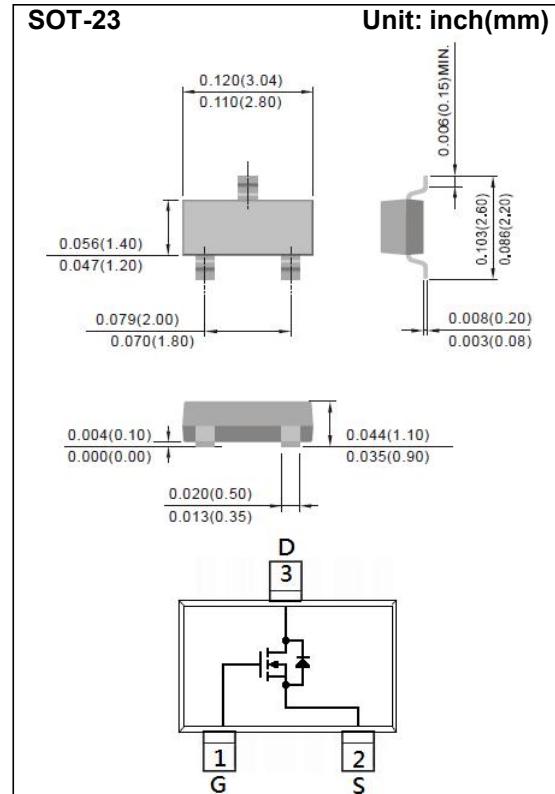
Voltage 30 V Current 5.8A

Features

- RDS(ON) , VGS@10V, ID@5.8A<30mΩ
- RDS(ON) , VGS@4.5V, ID@4.5A<38mΩ
- RDS(ON) , VGS@2.5V, ID@3.7A<50mΩ
- Advanced Trench Process Technology
- Pecially Designed for Switch Load, PWM Application etc

Mechanical Data

- Case: SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER | SYMBOL | LIMIT | UNITS |
|--|-----------------|----------|-------|
| Drain-Source Voltage | V_{DS} | 30 | V |
| Gate-Source Voltage | V_{GS} | ± 12 | V |
| Continuous Drain Current | I_D | 5.8 | A |
| Pulsed Drain Current | I_{DM} | 19.6 | A |
| Power Dissipation | P_D | 1.25 | W |
| | | 10 | mW/°C |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | -55~150 | °C |
| Typical Thermal resistance Junction to Ambient (Note 3) | $R_{\theta JA}$ | 100 | °C/W |

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Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS |
|---|-----------------------------------|---|------|----------|-----------|------------------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $\text{V}_{\text{GS}}=0\text{V}, \text{I}_D=250\mu\text{A}$ | 30 | - | - | V |
| Gate Threshold Voltage | $\text{V}_{\text{GS}(\text{th})}$ | $\text{V}_{\text{DS}}=\text{V}_{\text{GS}}, \text{I}_D=250\mu\text{A}$ | 0.5 | 0.84 | 1.3 | V |
| Drain-Source On-State Resistance | $\text{R}_{\text{DS}(\text{on})}$ | $\text{V}_{\text{GS}}=10\text{V}, \text{I}_D=5.8\text{A}$ | - | 28 | 30 | $\text{m}\Omega$ |
| | | $\text{V}_{\text{GS}}=4.5\text{V}, \text{I}_D=4.5\text{A}$ | - | 32 | 38 | |
| | | $\text{V}_{\text{GS}}=2.5\text{V}, \text{I}_D=3.7\text{A}$ | - | 45 | 50 | |
| Zero Gate Voltage Drain Current | I_{DSS} | $\text{V}_{\text{DS}}=30\text{V}, \text{V}_{\text{GS}}=0\text{V}$ | - | 0.01 | 1 | μA |
| Gate-Source Leakage Current | I_{GSS} | $\text{V}_{\text{GS}}=\pm 12\text{V}, \text{V}_{\text{DS}}=0\text{V}$ | - | ± 10 | ± 100 | nA |
| Dynamic | | | | | | |
| Total Gate Charge | Q_g | $\text{V}_{\text{DS}}=15\text{V}, \text{I}_D=5.8\text{A}, \text{V}_{\text{GS}}=10\text{V}$ (Note 1,2) | - | 5.7 | - | nC |
| Gate-Source Charge | Q_{gs} | | - | 1.1 | - | |
| Gate-Drain Charge | Q_{gd} | | - | 1.5 | - | |
| Input Capacitance | C_{iss} | $\text{V}_{\text{DS}}=15\text{V}, \text{V}_{\text{GS}}=0\text{V}, f=1.0\text{MHz}$ | - | 490 | - | pF |
| Output Capacitance | C_{oss} | | - | 44 | - | |
| Reverse Transfer Capacitance | Crss | | - | 32 | - | |
| Switching | | | | | | |
| Turn-On Delay Time | $\text{t}_{\text{d}(\text{on})}$ | $\text{V}_{\text{DD}}=15\text{V}, \text{I}_D=5.8\text{A}, \text{V}_{\text{GS}}=10\text{V}, \text{R}_G=3\Omega$ (Note 1,2) | - | 2 | - | ns |
| Turn-On Rise Time | tr | | - | 57 | - | |
| Turn-Off Delay Time | $\text{t}_{\text{d}(\text{off})}$ | | - | 78 | - | |
| Turn-Off Fall Time | tf | | - | 79 | - | |
| Drain-Source Diode | | | | | | |
| Maximum Continuous Drain-Source Diode Forward Current | I_s | --- | - | - | 1.5 | A |
| Diode Forward Voltage | V_{SD} | $\text{I}_s=1.0\text{A}, \text{V}_{\text{GS}}=0\text{V}$ | - | 0.77 | 1.2 | V |

NOTES :

1. Pulse width $\leq 300\mu\text{s}$, Duty cycle $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. R_{eJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
4. The maximum current rating is package limited

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TYPICAL CHARACTERISTIC CURVES

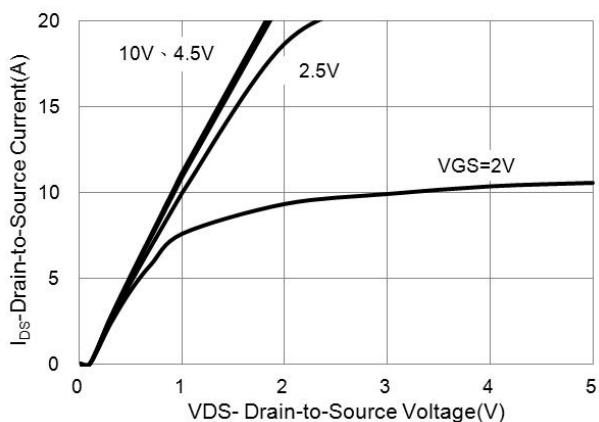


Fig.1 On-Region Characteristics

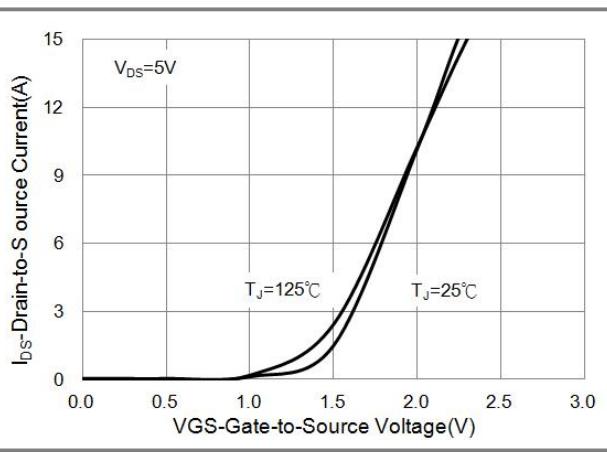


Fig.2 Transfer Characteristics

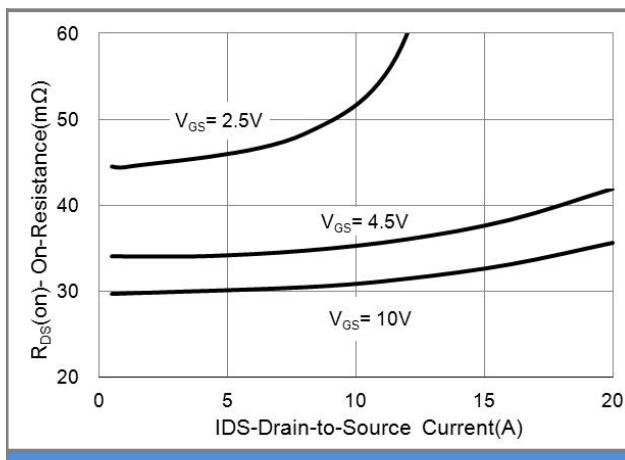


Fig.3 On-Resistance vs. Drain Current

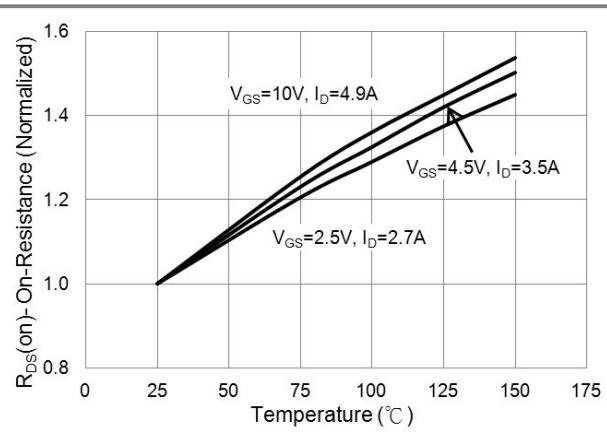


Fig.4 On-Resistance vs. Junction temperature

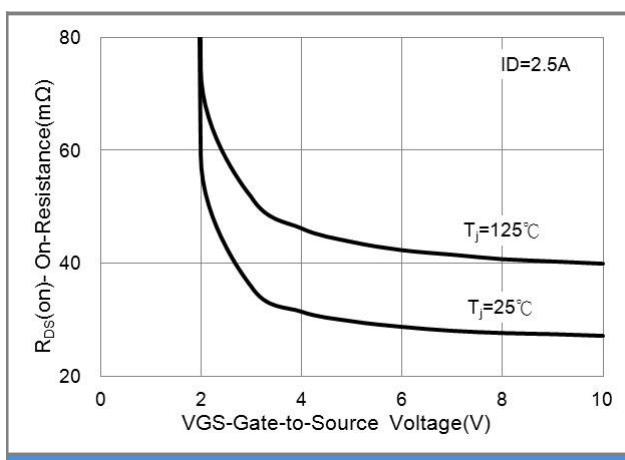


Fig.5 On-Resistance Variation with VGS.

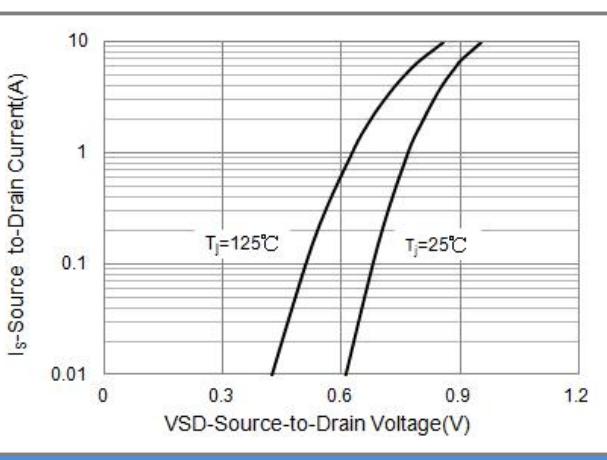
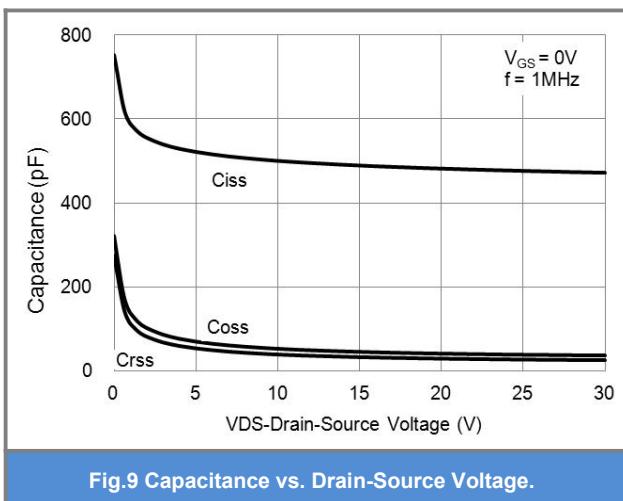
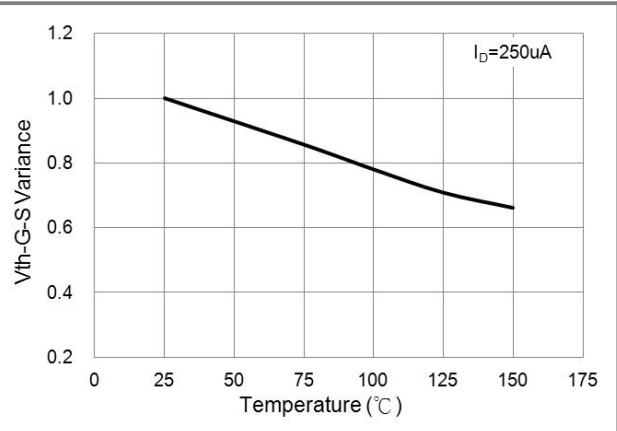
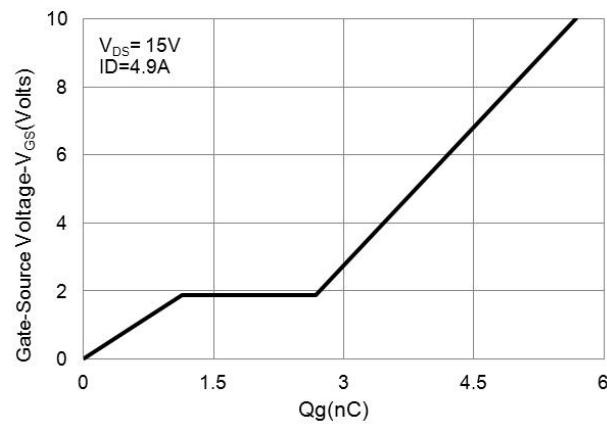


Fig.6 Body Diode Characteristics

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TYPICAL CHARACTERISTIC CURVES

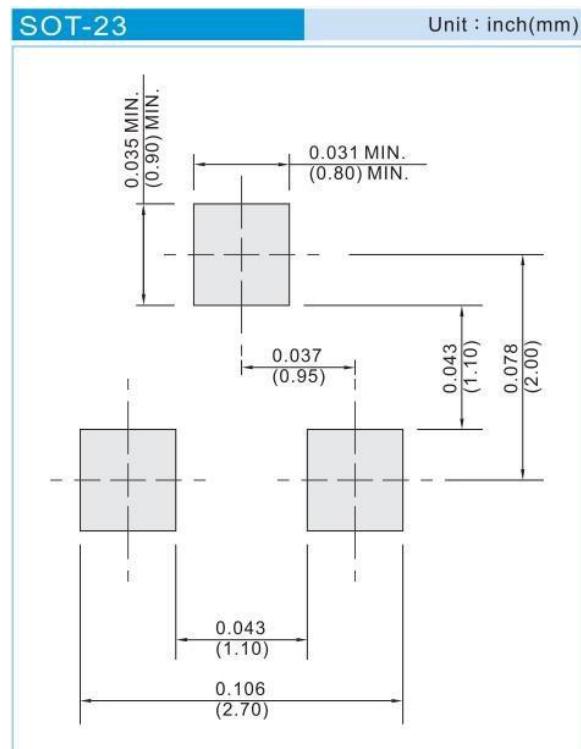


CSM3400S23

PART NO PACKING CODE VERSION

| Part No Packing Code | Package Type | Packing type |
|----------------------|--------------|------------------|
| CSM3400S23 | SOT-23 | 3K pcs / 7" reel |

MOUNTING PAD LAYOUT



CSM3400S23

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